

April 1995

15A, 100V - 200V Ultrafast Dual Diodes

Features

- Ultrafast with Soft Recovery Characteristic ($t_{RR} < 30\text{ns}$)
- +175°C Rated Junction Temperature
- Reverse Voltage Up to 200V
- Avalanche Energy Rated

Applications

- Switching Power Supply
- Power Switching Circuits
- General Purpose

Description

MUR3010PT, MUR3015PT, MUR3020PT and RURH1510CC, RURH1515CC, RURH1520CC are ultrafast dual diodes ($t_{RR} < 30\text{ns}$) with soft recovery characteristics. They have a low forward voltage drop and are of planar, silicon nitride passivated, ion-implanted, epitaxial construction.

These devices are intended for use as energy steering/ clamping diodes and rectifiers in a variety of switching power supplies and other power switching applications. Their low stored charge and ultrafast recovery with soft recovery characteristics minimizes ringing and electrical noise in many power switching circuits thus reducing power loss in the switching transistor.

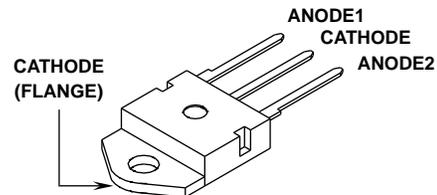
PACKAGING AVAILABILITY

| PART NUMBER | PACKAGE | BRAND |
|-------------|----------|-----------|
| MUR3010PT | TO-218AC | MUR3010PT |
| RURH1510CC | TO-218AC | RURH1510C |
| MUR3015PT | TO-218AC | MUR3015PT |
| RURH1515CC | TO-218AC | RURH1515C |
| MUR3020PT | TO-218AC | MUR3020PT |
| RURH1520CC | TO-218AC | RURH1520C |

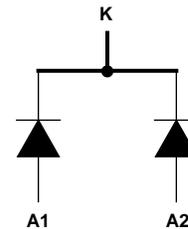
NOTE: When ordering, use the entire part number.

Package

JEDEC TO-218AC



Symbol



Absolute Maximum Ratings $T_C = +25^\circ\text{C}$

| | MUR3010PT RURH1510CC | MUR3015PT RURH1515CC | MUR3020PT RUR1520CC |
|--|-------------------------|-------------------------|------------------------|
| Peak Repetitive Reverse Voltage..... V_{RRM} | 100V | 150V | 200V |
| Working Peak Reverse Voltage..... V_{RWM} | 100V | 150V | 200V |
| DC Blocking Voltage..... V_R | 100V | 150V | 200V |
| Average Rectified Forward Current..... $I_{F(AV)}$ (Total device forward current at rated V_R and $T_C = 150^\circ\text{C}$) | 15A | 15A | 15A |
| Peak Forward Repetitive Current..... I_{FRM} (Rated V_R , square wave 20kHz) | 30A | 30A | 30A |
| Nonrepetitive Peak Surge Current..... I_{FSM} (Surge applied at rated load condition halfwave 1phase 60Hz) | 200A | 200A | 200A |
| Operating and Storage Temperature..... T_{STG}, T_J | -55°C to +175°C | -55°C to +175°C | -55°C to +175°C |

MUR3010PT, MUR3015PT, MUR3020PT, RURH1510CC, RURH1515CC, RURH1520CC

Electrical Specifications $T_C = +25^\circ\text{C}$, Unless Otherwise Specified

| SYMBOL | TEST CONDITION | LIMITS | | | | | | | | | UNITS |
|--|--|-----------------------|-----|------|-----------------------|-----|------|-----------------------|-----|------|--------------------|
| | | MUR3010PT, RURH1510CC | | | MUR3015PT, RURH1515CC | | | MUR3020PT, RURH1520CC | | | |
| | | MIN | TYP | MAX | MIN | TYP | MAX | MIN | TYP | MAX | |
| V_F | $I_F = 15\text{A}$ $T_C = +150^\circ\text{C}$ | - | - | 0.85 | - | - | 0.85 | - | - | 0.85 | V |
| | $I_F = 15\text{A}$ $T_C = +25^\circ\text{C}$ | - | - | 1.05 | - | - | 1.05 | - | - | 1.05 | V |
| I_R at $T_C = +150^\circ\text{C}$ | $V_R = 100\text{V}$ | - | - | 500 | - | - | - | - | - | - | μA |
| | $V_R = 150\text{V}$ | - | - | - | - | - | 500 | - | - | - | μA |
| | $V_R = 200\text{V}$ | - | - | - | - | - | - | - | - | 500 | μA |
| I_R at $T_C = +25^\circ\text{C}$ | $V_R = 100\text{V}$ | - | - | 100 | - | - | - | - | - | - | μA |
| | $V_R = 150\text{V}$ | - | - | - | - | - | 100 | - | - | - | μA |
| | $V_R = 200\text{V}$ | - | - | - | - | - | - | - | - | 100 | μA |
| t_{RR} | $I_F = 1\text{A}$ | - | - | 30 | - | - | 30 | - | - | 30 | ns |
| | $I_F = 15\text{A}$ | - | - | 35 | - | - | 35 | - | - | 35 | ns |
| t_A | $I_F = 1\text{A}$ | - | 18 | - | - | 18 | - | - | 18 | - | ns |
| | $I_F = 15\text{A}$ | - | 20 | - | - | 20 | - | - | 20 | - | ns |
| t_B | $I_F = 1\text{A}$ | - | 9 | - | - | 9 | - | - | 9 | - | ns |
| | $I_F = 15\text{A}$ | - | 10 | - | - | 10 | - | - | 10 | - | ns |
| $R_{\theta JC}$ | | - | - | 1.5 | - | - | 1.5 | - | - | 1.5 | $^\circ\text{C/W}$ |
| E_{AVL} | see Fig. 7, 8 | - | - | 20 | - | - | 20 | - | - | 20 | mj |

DEFINITIONS

V_F = Instantaneous forward voltage (pw = 300 μs , D = 2%).

I_R = Instantaneous reverse current.

t_{RR} = Reverse recovery time at $di_F/dt = 100\text{A}/\mu\text{s}$ (See Figure 2), summation of $t_A + t_B$.

t_A = Time to reach peak reverse current at $di_F/dt = 100\text{A}/\mu\text{s}$ (See Figure 2).

t_B = Time from peak I_{RM} to projected zero crossing of I_{RM} based on a straight line from peak I_{RM} through 25% of I_{RM} (See Figure 2).

$R_{\theta JC}$ = Thermal resistance junction to case.

E_{AVL} = Controlled avalanche energy (See Figures 7 and 8).

pw = pulse width.

D = duty cycle.

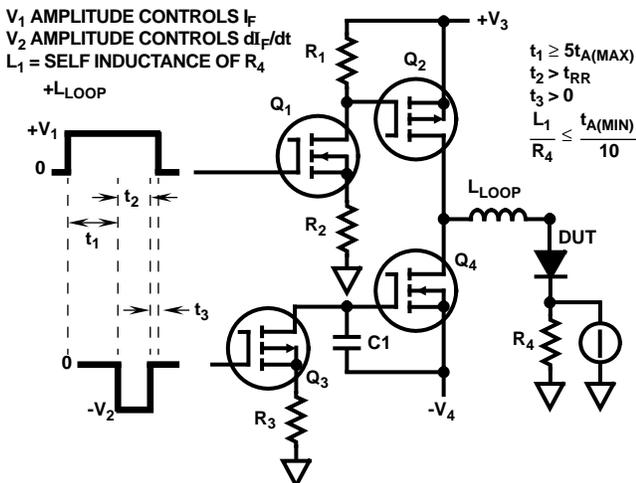


FIGURE 1. t_{RR} TEST CIRCUIT

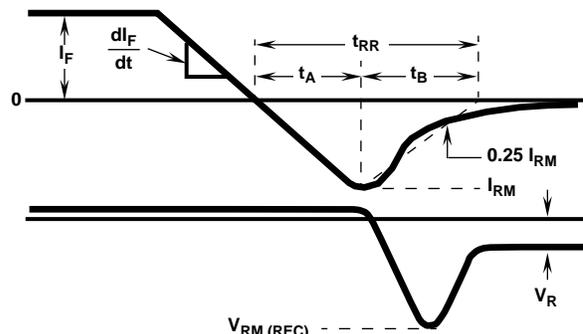


FIGURE 2. DEFINITIONS OF t_{RR} , t_A AND t_B

Typical Performance Curves

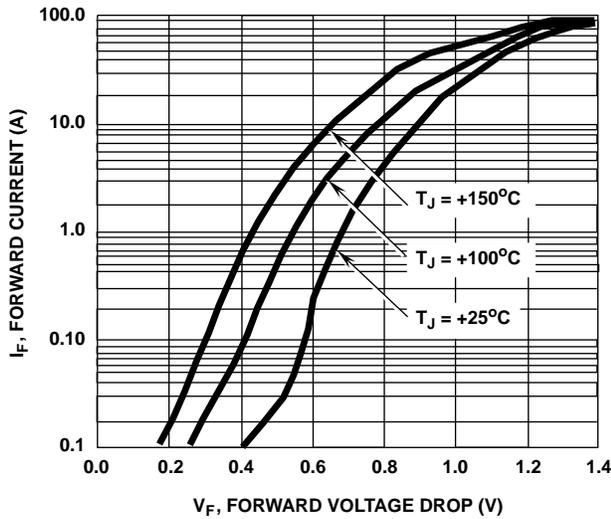


FIGURE 3. FORWARD VOLTAGE vs FORWARD CURRENT CHARACTERISTIC

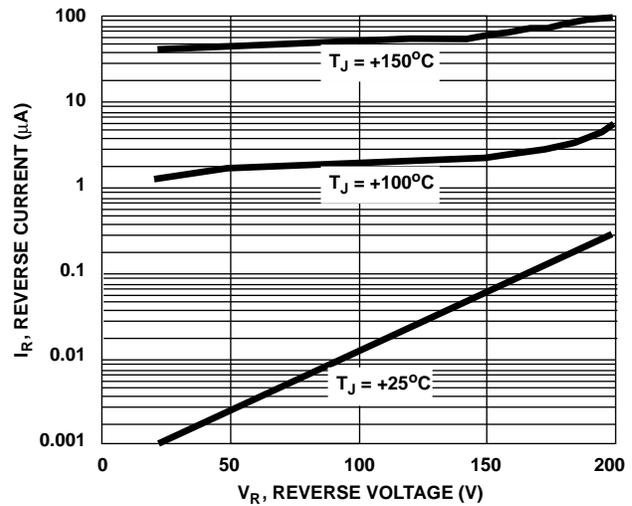


FIGURE 4. REVERSE VOLTAGE vs REVERSE CURRENT CHARACTERISTIC

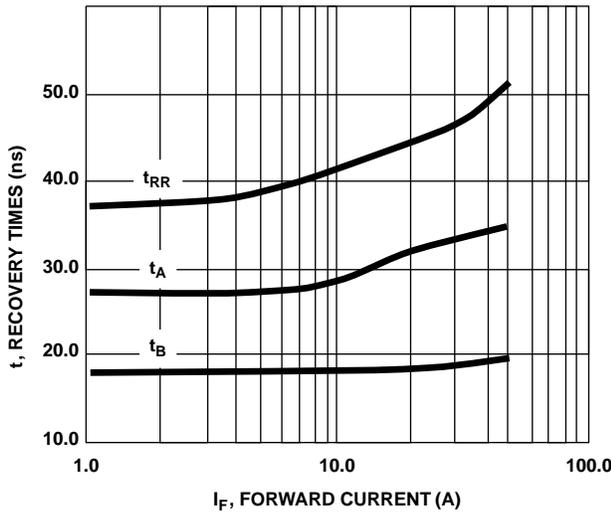


FIGURE 5. TYPICAL t_{RR} , t_A AND t_B CURVES vs FORWARD CURRENT

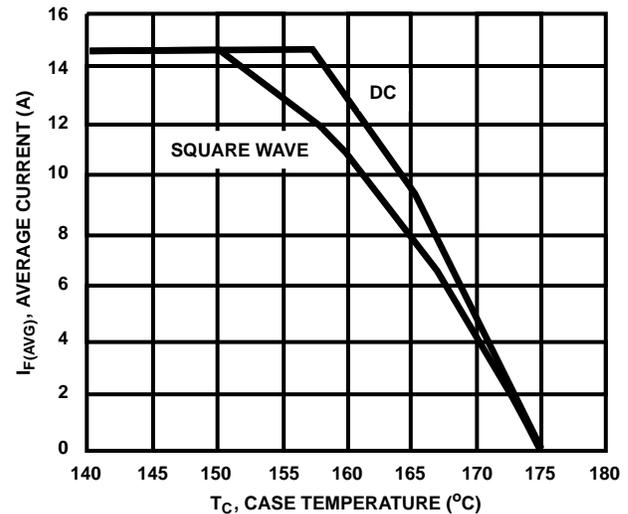


FIGURE 6. TYPICAL CURRENT DERATING CURVE vs CASE TEMPERATURE

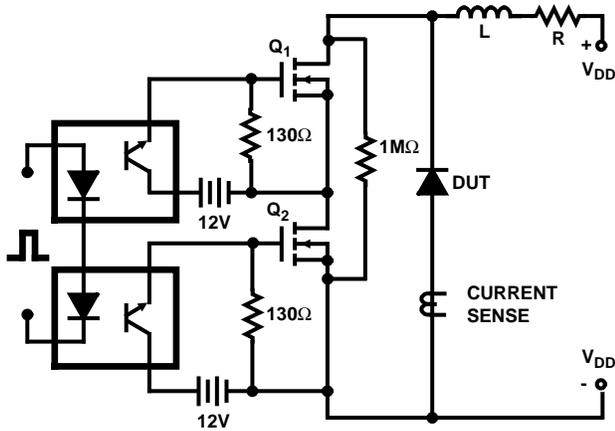


FIGURE 7. AVALANCHE ENERGY TEST CIRCUIT

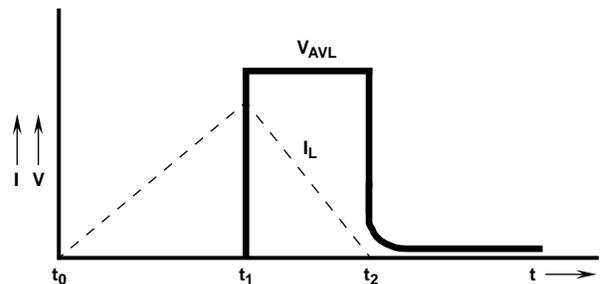


FIGURE 8. CURRENT VOLTAGE WAVEFORM

$$I_{L \text{ PEAK}} = 1A, L = 40mH, R < 0.1W, E_{AVL} = 1/2LI^2 [V_{AVL}/(V_{AVL} - V_{DD})]$$